

Vishay Semiconductors

RoHS

COMPLIANT

HALOGEN

FREE

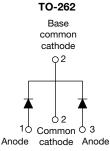
# Schottky Rectifier, 2 x 20 A



# D<sup>2</sup>PAK Base common cathode O 2 1 Common O 3 node cathode Anode

VS-40CTQ150SPbF



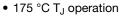


VS-40CTQ150-1PbF

PRODUCT SUMMARY					
Package	TO-262AA, TO-263AB (D <sup>2</sup> PAK)				
I <sub>F(AV)</sub>	2 x 20 A				
$V_{R}$	150 V				
V <sub>F</sub> at I <sub>F</sub>	0.71 V				
I <sub>RM</sub>	15 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	1 mJ				

### **FEATURES**

- AEC-Q101 qualified
- Very low forward voltage drop
- Halogen-free according to IEC 61249-2-21 definition



- Center tap TO-220 package
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

#### **DESCRIPTION**

The VS-40CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	40	А		
V <sub>RRM</sub>		150	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1500	А		
$V_{F}$	20 Apk, T <sub>J</sub> = 125 °C (per leg)	0.71	V		
TJ		- 55 to 175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-40CTQ150SPbF VS-40CTQ150-1PbF	UNITS	
Maximum DC reverse voltage	$V_{R}$	150	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	150	V	

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average pe	er leg	I <sub>F(AV)</sub> 50 % duty cycle at T <sub>C</sub> = 140 °C, rectangular waveform		20		
See fig. 5 per de			, rectangular wavelorm 40		^	
Maximum peak one cycle non-repetitiv surge current per leg		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500	A	
See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	250		
Non-repetitive avalanche energy per le	g E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 1.5  \text{A},  L = 0.9$	mH	1.0	mJ	
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxim		1.5	Α	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		
		20 A	T <sub>.1</sub> = 25 °C	0.93	
Maximum forward voltage drop per leg	V (1)	40 A	1 <sub>J</sub> =25 C	1.16	V
See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	20 A	T 105 °C	0.71	
		40 A	T <sub>J</sub> = 125 °C	0.85	
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	50	μΑ
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = nateu V <sub>R</sub>	15	mA
Maximum junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	ge 100 kHz to 1 MHz), 25 °C	450	pF
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body 8.0		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	Rated V <sub>R</sub> 10 000 V		

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg  Maximum thermal resistance, junction to case per package		В	DC operation See fig. 4	1.5	
		R <sub>thJC</sub>	DC operation 0	0.75	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.5	
Annyayimata wajaht				2	g
Approximate weight				0.07	OZ.
Manustina taurus	minimum		No. of the signatural statements	6 (5)	kgf · cm
Mounting torque	maximum		Non-lubricated threads		(lbf $\cdot$ in)
Marking davisa			Case style D <sup>2</sup> PAK	40CTC	Q150S
Marking device			Case style TO-262	40CTC	150-1



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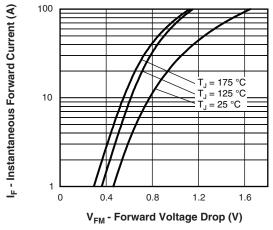


Fig. 1 - Maximum Forward Voltage Drop Characteristics

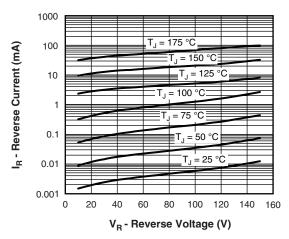


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

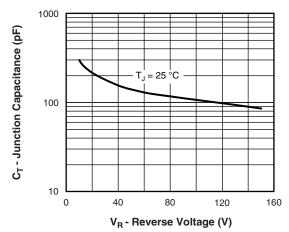


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

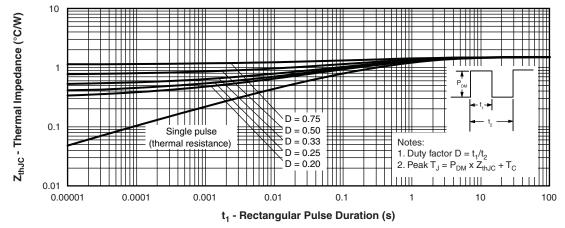


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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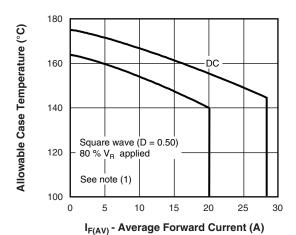


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

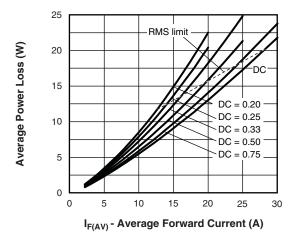


Fig. 6 - Forward Power Loss Characteristics

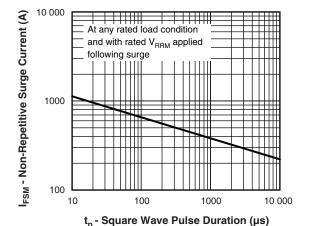


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \% V_R \text{ applied} \\ \end{array}$ 

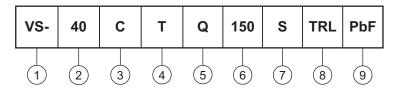
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Schottky Rectifier, 2 x 20 A

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# **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Current rating (40 A)
- Circuit configuration:

C = Common cathode

- 4 T = TO-220
- 5 Schottky "Q" series
- Voltage rating (150 = 150 V)
- 7 • S = D<sup>2</sup>PAK
  - -1 = TO-262
- 8 • None = Tube (50 pieces)
  - TRL = Tape and reel (left oriented for D<sup>2</sup>PAK only)
  - TRR = Tape and reel (right oriented for D2PAK only)
- 9 PbF = Lead (Pb)-free

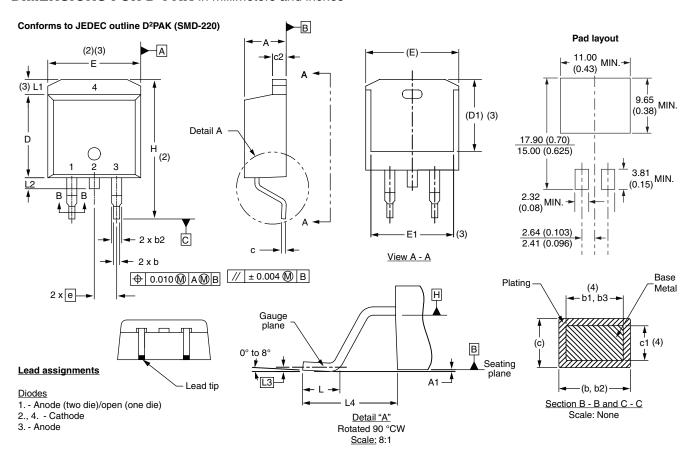
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?95434			



# Vishay High Power Products

# D<sup>2</sup>PAK, TO-262

# **DIMENSIONS FOR D<sup>2</sup>PAK** in millimeters and inches



OVII DOI	MILLIM	IETERS	INC		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

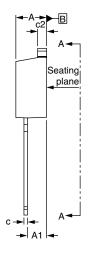
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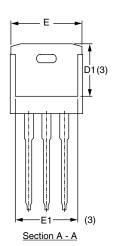
D<sup>2</sup>PAK, TO-262



### **DIMENSIONS FOR TO-262** in millimeters and inches

# 





**⊕** 0.010**⋒**|A**⋒**|B

#### Lead assignments

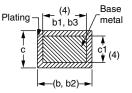


#### <u>Diodes</u>

-3 x b2 --3 x b

> 1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

OVMDOL	MILLIMETERS		INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.10	0 BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline





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